High Isolation Gate Drive Transformers





- Rugged design for Industrial Applications
- UL recognized, TUV approved to IEC 60950
- Up to 4250Vrms gate to drive isolation
- IEC 61558, IEC 61010 & IEC 60601 reinforced insulation compliant designs

| Electrical Specifications @ 25°C - Operating Temperature -40°C to +125°C | | | | | | | | | | | |
|--|----------------|-----------------------------|---|--|---|-------------------------------|-----------------------------|----------------------------|--|--|--|
| Part ^{3,4} Number | Turns Ratio | ET (V * µsec MAX) | Primary Inductance (1-10) (µH MIN) | Leakage Inductance Gate to Drive (µH MAX) | DCR Drive (1-10) (mΩ ±20%) | DCR Gates (mΩ ±20%) | Hi-Pot | | | | |
| | | | | | | | Drive-Gate (Vrms) | Gate-Gate (Vrms) | | | |
| P0584NL | 1:1:1 | 92 | 450 | 0.5 | 80 | 72 | 3000 | 1500 | | | |
| P0585NL | 1:1:1:1:1 | 92 | 450 | 1.3 | 330 | 180 | 3000 | 1500* | | | |
| P0584ANL | 1:1:1 | 114 | 686 | 0.8 | 710 | 710 | 4250 | 1500 | | | |
| P0585ANL | 1:1:1:1:1 | 114 | 686 | 2.2 | 710 | 710 | 4250 | 1500* | | | |

Notes:

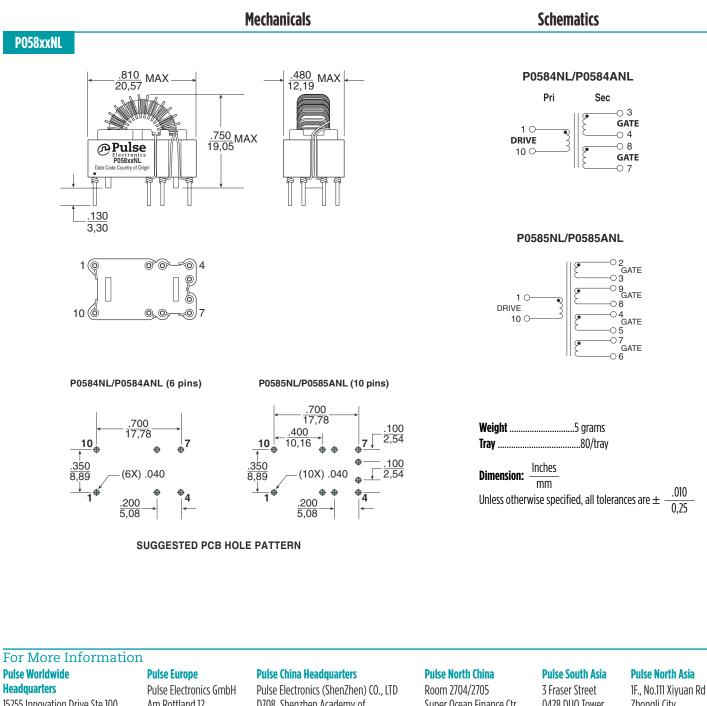
- The max ET is calculated to limit the core loss and temperature rise at 100KHz based on a bipolar flux swing of 180mT Peak. The applied ET may need to be derated for higher frequencies based on the temperature rise which results from the core and copper losses.
- 2. The temperature rise of the component is calculated based on the total core loss and copper loss:
 - A. To calculate total copper loss (W), use the following formula: Copper Loss (W) = Irms² * (DCR_Drive + (# of Gates) * DCR_Gates)
 - B. To calculate total core loss (W), use the following formula: Core Loss (W) = 6.5E-10*(Frequency in kHz)^{1.67*}(180 * [ET/ET Max])^{2.53} Where ET is the applied Volt Second, ET Max is the rated Volt Second for 180mT flux swing
 - C. To calculate temperature rise, use the following formula: Temperature Rise (C) = 63 * (Core Loss(W) + Copper Loss (W))

- 3. 500Vrms Hi-Pot between pins 5 & 6.
- NL versions, which use triple insulated Teflon wire on the drive winding and magnetic wire on the gate windings, are TUV certified. 600Vrms isolation rating is provided between drive and gate windings.

ANL versions, which use triple insulated wire on both the drive and gate windings, are compliant with IEC 61558, IEC 61010 & IEC 60601. 1000Vrms isolation rating is provided between all winding except those terminate to pins 5 & 6.

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| 15255 Innovation Drive Ste 100 San Diego, CA 92128 U.S.A. | Am Rottland 12 58540 Meinerzhagen Germany | D708, Shenzhen Academy of Aerospace Technology, The 10th Keji South Road, Nanshan District, Shenzhen, P.R. China 518057 | Super Ocean Finance Ctr. 2067 Yan An Road West Shanghai 200336 China | 0428 DUO Tower Singapore 189352 | Zhongli City Taoyuan City 32057 Taiwan (R.O.C) |
|---|---|---|---|------------------------------------|--|
| Tel: 858 674 8100 | Tel: 49 2354 777 100 | Tel: 86 755 33966678 | Tel: 86 21 62787060 | Tel: 65 6287 8998 | Tel: 886 3 4356768 |
| Fax: 858 674 8262 | Fax: 49 2354 777 168 | Fax: 86 755 33966700 | Fax: 86 2162786973 | Fax: 65 6280 0080 | Fax: 886 3 4356820 |

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